NSN 5961-01-260-3866

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-260-3866 **Inclosure Material:** Plastic **Overall Length:** 0.770 inches **Terminal Length:** 0.200 inches **Overall Height:** 0.150 inches **Overall Width:** 0.260 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 20.0 collector to base voltage/static/emitter open all transistor and 15.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 40.00 milliamperes zero-gate-voltage source current preset all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No